NSN 5961-00-421-6417

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-421-6417 **Inclosure Material:** Metal and glass **Overall Length:** 0.250 inches **Overall Diameter:** 0.085 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 6.8 regulator voltage **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 13499-353-6456 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: